PRODUCTS & Solutions























PRESENTATION

EXXELIA is a leading designer and manufacturer of high-reliability passive components and electromechanical solutions. EXXELIA was born in 2009 from the merge of several long-established companies with complementary activities and know-hows.

This powerful alliance of expertise enables the Group to provide a **unique and complete product portfolio** commonly used for power electronics, power generation, energy storage, and signal filtering functions in **harsh environments**.



EXPANDING PRODUCT PORTFOLIO



Capacitors





Ceramic & Tantalum Capacitors



Magnetics



RF & Microwave Components



EMI/EMC Filters



Position Sensors & Slip Rings



Precision Mechanics

FROM STANDARD TO CUSTOM DESIGNS

EXXELIA has earned international recognition in designing and manufacturing custom passive components that deliver the required performance for any application. As a high-end supplier, **EXXELIA** is involved in most major programs in space, defense and civil aviation industries.

7 MARKETS







Space



Defense



Transport & Energy



Telecom



Medical



Industry

10 COMPANIES, 1 BRAND

Eurofarad	Exxelia Technologies
Microspire	Exxelia Magnetics
N'Ergy	Exxelia Magnetics
Firadec	ExxeliaTantalum
Sic-Safco	Exxelia Sic Safco
Temex Ceramics	Exxelia Temex
Astema	Exxelia Maroc
Dearborn	Exxelia Dearborn
Raf Tabtronics	Exxelia Raf Tabtronics
DeYoung Mfg	Exxelia DeYoung

EXXELIA AT A GLANCE



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Employees

ISO 9001 EN 9100 AS 9100 Certified Manufacturing Locations



Expertise since **1921**



EXXELIA WORLDWIDE

EXXELIA is a global company with manufacturing sites strategically located to cover all continents. Three assembly plants are established in competitive manufacturing countries, enabling the group to provide cost-effective solutions. Thanks to an

extensive sales network covering more than 30 countries, EXXELIA is able to provide prompt in-depth technical expertise throughout a project and remain close to its clients at all stages from design to production.

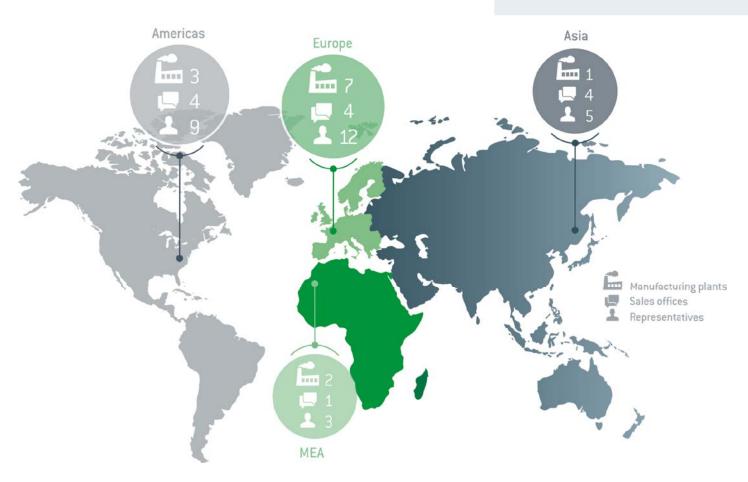
OUR APPROACH

EXXELIA focuses its know-how on challenging markets that require high level of technicity and reliability. Our approach is based on three key principles:

FOCUS: serving a limited number of defined markets to deeply understand the needs of those markets.

INNOVATION: Provide new and creative value propositions combining the right products with the expected level of service.

RESPONSIVENESS: Worldwide presence of our sales, design and production departments for optimized response time.



CERAMIC CAPACITORS



CERAMIC CAPACITORS:

The term «Ceramic capacitor» refers to the dielectric used to make capacitors. The type of ceramic used is a synthetic material obtained by submitting a mixture of carefully selected oxides to a high temperature treatment.

Multi-layer ceramic capacitors are made in the form of monolithic block and contain interleaved metal electrodes. These electrodes are alternately exposed on opposite sides of the package.

Their excellent temperature resistance, high volume/capacitance ratio, electrical properties and reliability make these components ideal for a wide range of applications including medical implants, aircraft flight controls, switch-mode power supply in harsh environments, core samplers for petroleum exploration, and space vehicles.

CUSTOM DESIGN CAPACITORS:

As the world's leading manufacturer of specific passive components, we stand apart through our ability to quickly evaluate the application specific engineering challenges and provide a cost-effective and efficient solutions.



For requirements that cannot be met by catalog products, we offer leading edge solutions in custom configuration: custom geometries, packaging, characteristics, all is possible thanks to our extensive experience and robust development process, while maintaining the highest level of reliability.





Where necessary, special testing is done to verify requirements, such as low dielectric absorption, ultra-high insulation resistance, low dissipation factor, stability under temperature cycling or under specified environmental conditions, etc.



		T°	Product range (space grade available in green)
	"0	52°C	CEC / CNC
	Chips	-55°C+125°C	CEC Y (polymer termination)
		- 5	CNC Y (polymer termination)
	hips	25°C	CER / CNR 14 - 2 - 12 - CEL / CNL 14 - 2 - 12
	Custom chips	-55°C +125°C	C3E-C4E-C3N-C4N
	ä	5 <u> </u>	BPM 12 - BPM 22 - TBC 177 TBC 277 BPM 224 - BPM 24
			TCE 11 - TCE 13 - TCE 61 to TCE 64
Standard	ass 1	25°C	TCE 50/60 - CC 05/06
Star	Molded class 1	-55°C +125°C	TCE 52 to TCE 54
	Molo	-21	TCE 72 to TCE 80
			LA 1 to LA 5
			TCN 52 to TCN 55
	ss 2	52°C	TCN 72 to TCN 80
	Molded class 2	-55°C +125°C	TCN 19 - TCN 50/60 - TCN 30 - TCN 31 - TCN 61 to TCN 64
	Mold	-55	LA 6 A - LA 6 B
			CK 05 - CK 06
on netic	Chips	55°C+125°C	R14 to S47
Non magnetic	Rad.	–55°C	S43 to S47
	Stacks Chips		C 178 to 189 - C 278 to 289
			C 479 to 488
age		J.27	CS 181 to CS 188 - CS 281 to CS 288
h volt	Sta	3°C + 1.	CS 481 to CS 488
Hig	_	-26	TCF 178 to 188-TCF 278 to 288 - TKD 179 to 185 - TKD 279 to 285
	Molded		TCK 179 to 188-TCK 279 to 288 - TCL 179 to 188 - TCL 279 to 288
			TCF 479 to 488 - TCK 479 to 488 - TCL 479 to 488
	Chips		R2225 to R45107
-	Radial		R2225 to R8060
itance	Ra	52°C	TEP/TEV 53 to 65
High capacitance	"	-55°C +125°C	SC00 to SC18 - SV01 to SV07 - CNC31 to 34
High	Stacks	-2	CNC53 to CNC 65
			CEC53 to 65
	Self prot. Mold. Chips Block		TCN83 - TCN86 - TCN87
	Chips	_55°C +250°C	CEC 203 to CEC 233 - CNC 203 to CNC 233 - CE/CN2X - CE/CN5X
inre	Mold	ري	TCE/TCN 201 to 204 - TCE/TCN 252 to 254
nperat	prot.	+200	TCE 212 to TCE 216 - TCN 212 to TCN 216
High temperature		–55°C +200°	TCE 263 to TCE 266 - TCN 263 to TCN 266
Ξ	Rad.		TCH 279 to TCH 285
	Chips/Rad. or ribbon leads Stacks Rad.	_55°C +215°C	SCT00 to SCT18
ors	n leads		SPT 519
Power capacitors	rribbo	-55°C +125°C	CAW 54 to CAW 65
wer c	/Rad. o	_55°C	CEW 54 to CEW 65
Po	Chips/		CNW 32

Dielectric material	tric material Capacitance Voltage Capacitance Voltage		Tolerance	Use		
NPO - 2C1 - X7R	1 pF ⇒ 10 μF	16 V ➡ 1 000 V	1 pF ➡ 3.9 μF	10 V ⇒ 1 000 V	±1% ⇒ ±20%	
NP0	1 pF ➡ 180 nF	16 V ⇒ 1 000 V	1 pF ➡ 68 nF	10 V ➡ 100 V	±1% ⇒ ±20%	Precision, stability,
2C1 - X7R	' 10 pF ➪ 10 μF	16 V ⇒ 1 000 V	' 10 pF ➡ 3.9 μF	10 V ➡ 100 V	±5% ⇒ ±20%	decoupling, SMD.
NPO - 2C1 - X7R	1 pF ➡ 270 nF	16 V ➡ 100 V			±1% ⇒ ±20%	Low inductance, Low profile.
NPO - 2C1 - X7R	4.7 pF ⇔ 33 nF	25 V ⇔ 200 V			±1% ⇒ ±20%	Capacitance arrays.
NPO - X7R	' 10 pF ➡ 4.7 μF	25 V ➡ 500 V			±5% ⇒ ±20%	Feed through filters.
NPO - N150	0.5 pF ⇒ 47 nF	50 V ⇒ 100 V			±1% ⇒ ±20%	, and the second
NPO	' 1 pF ➡ 22 nF	50 V ➡ 200 V			±1% ⇒ ±10%	Procision stability
NPO	' 1 pF ➡ 10 nF	63 V ⇒ 100 V			±0.5% ⇒ ±20%	Precision, stability, epoxy resin molded,
NPO	1 pF ➡ 100 nF	63 V ⇒ 200 V			±1% ⇒ ±20%	through hole components. Axial & Radial leads.
Several	1 pF ➡ 680 nF	25 V ⇒ 63 V			±1% ⇒ ±20%	
2C1 - X7R	10 pF ⇒ 470 nF	63 V ⇒ 500 V			±5% ⇒ ±20%	
2C1 - 2C2	22 pF ➡ 4.7 μF	50 V ⇒ 200 V			±10% ⇒ ±20%	
201	10 pF ⇒ 2.2 μF	25 V ⇔ 250 V			±5% ⇒ ±20%	Decoupling, epoxy resin molded,
201	100 pF ⇒ 1 μF	25 V ⇒ 63 V			±5% ⇒ ±20%	through hole components. Axial and radial leads.
BX	10 pF ⇒ 1 μF	50 V ⇒ 200 V			±10% ⇒ ±20%	
X7R - NPO	10 pF ⇒ 1 μF	63 V ⇒ 500 V			±1% ⇒ ±20%	Non magnetic components
X7R - NPO	180 pF ⇒ 1 μF	63 V ⇒ 500 V			±1% ⇒ ±20%	for Medical applications: • MRI systems and RF generators for MRI
NPO - X7R		200 V ➡ 10 000 V	10 ~	250 V ➡ 10 000 V	±1% ⇒ ±20%	X-ray systems & power suppliers for X-ray
N2200	10 pF ⇔ 39 μF 22 pF ⇔ 10 μF	200 V ⇒ 10 000 V	10 pF ⇔ 6.8 μF 22 pF ⇔ 10 μF	200 V ⇒ 5 000 V	±5% ⇒ ±20%	
NPO - X7R	1 nF ⇒ 15 μF	1 000 V ⇒ 10 000 V	22 βι → 10 μι	200 7 7 3 000 7	±10% ⇒ ±20%	Power supply,
						voltage multiplier, radars. • aeronautic
N2200	1.2 nF ⇔ 47 μF	200 V ⇒ 5 000 V	10 F C 0 11 F	3E0 V 🖒 10 000 V	±5% ➡ ±20%	• space • defense
NPO - XZR	10 pF → 39 μF	200 V → 10 000 V	10 pF ⇒ 6.8 μF	250 V → 10 000 V	±5% ➡ ±20%	• railways
NPO - X7R	10 pF ⇒ 39 μF	200 V → 10 000 V	10 pF ⇒ 6.8 μF	250 V ➡ 10 000 V	±5% ⇒ ±20%	
N2200	22 pF ➡ 10 μF	200 V ⇒ 5 000 V			±5% ⇒ ±20%	
X7R	47 nF ⇒ 270 μF	50 V → 500 V			±10% ⇒ ±20%	
X7R	47 nF ⇒ 270 μF	50 V → 500 V			±10% ⇒ ±20%	Power cumply
NPO	10 nF ⇒ 6.8 μF	63 V → 500 V	12.5 12.5	467 1 257	±10% ⇒ ±20%	Power supply, filtering, smoothing, decoupling.
X7R	47 nF ⇒ 400 μF	16 V ⇒ 500 V	1.2μF ⇒ 68 μF	16 V ⇒ 25 V	±10% ⇒ ±20%	• aeronautic • space
X7R	100 nF ➡ 180 μF	50 V → 500 V	100 nF ➡ 180 μF	50 V → 500 V		• defense
NP0	10 nF ➡ 6.8 μF	63 V ⇒ 500 V	10 nF 🕏 6,8 nF	50 V ➡ 500 V	±10% ⇒ ±20%	
X7R	680 nF 🕏 120 μF	50 V ➡ 500 V			±10% ⇒ ±20%	
NPO - X7R	1 pF ➪ 5.6 μF	16 V ⇒ 100 V			±1% ⇒ ±20%	
NPO - X7R	1 pF ➡ 1.5 μF	50 V ➡ 100 V			±1% ⇒ ±20%	High temperature, ● SMD
NPO - X7R	10 pF ➡ 3.9 μF	50 V ➡ 100 V			±5% ⇒ ±20%	high capacitance
NPO - X7R	1 pF ⇔ 3.3 μF	25 V ⇒ 500 V			±2% ⇒ ±20%	high voltage self protected
X7R	100 pF ⇔ 2.7 μF	200 V ⇒ 3 000 V			±10% ⇒ ±20%	oil drilling, motor control.
X7R	47 nF ⇒ 400 μF	16 V ⇒ 500 V			±10% ±20%	
NP0	10 pF ➡ 5600 pF	550 V ⇒ 6 300 V			±5% ⇒ ±10%	HF - VHF transmission,
P100	1 pF ➡ 10 nF	1 000 V ⇒ 3 600 V			±5% ⇒ ±10%	antenna tuning. • low losses
NPO	4.7 pF ⇒ 15 nF	1 000 V ⇒ 3 600 V			±5% ⇒ ±10%	high current high voltage
X7R	10 nF ⇒ 1 μF	100 V ➪ 300 V			±10% ⇒ ±20%	

High-Q CAPACITORS

Wide choice of ceramic multi-layer and single layer capacitors mostly intended for applications requiring low losses (low ESR - high Q factor) in a given range of working frequencies and for a specified DC or RF voltage. Capacitors are available either as "chip" or with leads or ribbons. **EXXELIA** TEMEX is also providing special connections for customized solutions.

The very well known "High Q" series CHA (0505) and CHB (1111) widely used in the world are completed with the "super High Q SHA & SHB" ultra-stable NPO dielectric for a direct superseding when needed. EIA sizes 0402 (SHL) 0603 (SHS) 0805 (SHF) 1206 (SHN) and 1210 (SHT) 250 to 1000 V rated versus selected capacitance are also available. These sizes are mainly used in base stations, power amplifiers, filters and broadcasting.

Frequency range : some MHz up to several GHz. All ranges are RoHS and are also available with non-magnetic terminations.

For High power, high Voltage applications (MRI, NMR, RF generators for laser, plasma applications, power filters), EXXELIA TEMEX propose CP and CL series with two stable dielectric types (NPO and P9O) with voltages ranging from 1000 to 7000 V (special range for 5 000 Vrms or more guaranteed). Special assemblies with ribbons are available and can be studied with customers versus actual design consideration.

Non-magnetic terminations also available.







	T°	Туре	Product range	Temperature coeff.	Extended temp.*	Capacitance	Tolerance *	Standard voltage *	Use
		CHA	0505	P100 (100 ±30ppm/°C)		0.1 ⇒ 100 pF		250 V	Callular has a station amplifier MDI
		CHB	1111	P100 (100 \pm 30ppm/°C)	Up to +175°C	0.2 ⇒ 1 000 pF		500 V	Cellular base station amplifier, MRI
w		SHA	0505	NP0 (0 \pm 30ppm/°C)		0.2 ⇒ 100 pF		250 V	
itor		SHB	1111	NP0 (0 \pm 30ppm/°C)	Up to +175°C	0.3 ⇒ 1 000 pF		500 V	
Capacitors	ړ	SHL	0402	NP0 (0 \pm 30ppm/°C)		0.1 ⇒ 33 pF		200 V	
ESR 0	-55°C +125°C	SHS	0603	NP0 (0 \pm 30ppm/°C)		0.1 ⇒ 100 pF	±0.05pF	250 V	Cellular base station equipment,
ow E		SHF	0805	NP0 (0 \pm 30ppm/°C)		0.3 ⇒ 220 pF	±10%	250 V	Broadband,
		SHN	1206	NP0 (0 \pm 30ppm/°C)		0.5 ⇒ 220 pF		500 V	Point to point/ multi-point radios, RF generators
RF MLCC, low		SHT	1210	NP0 (0 \pm 30ppm/°C)		1 ➡ 1 000 pF		500 V	Ü
Œ		SHD	0711	NP0 (0 \pm 30ppm/°C)	Up to +175°C	0.5 ⇒ 100 pF		500 V	
		SHR	0709	NP0 (0 \pm 30ppm/°C)	Up to +175°C	0.5 ⇒ 100 pF		500 V	
		NHB	1111	NP0 (0 \pm 30ppm/°C)	Up to +175°C	0.3 ⇒ 100 pF		500 V	
. s		CPX	2225	P100 (100 ±30)		0.5 ⇒ 2 700pF		2 500 V	
ower citors fact	+125°C	CPE	4040	P100 (100 \pm 30)		1 ➡ 10 000 pF	±0.1pF	3 600 V	RF power amplifier, Plasma chamber,
RF power capacitors High () factor	55°C	CLX	2225	NP0 (0 ± 30)		0.3 ⇒ 2 700 pF	±20%	2 500 V	MRI coils
°Ξ	i,	CLE	4040	NP0 (0 ± 30)		1 ➡ 10 000 pF		3 600 V	

* Depending on capacitance value. Available extended voltage on request.

MICROWAVE COMPONENTS

FREQUENCY TUNING ELEMENTS:

Those special elements are intended for adjusting a circuit made /using cavities: inserted in the cavity, their capacitive, resistive or inductive characteristics are used to tune the filter accordingly. The "self-locking" system primordial for stability in application when filters are located in outdoor cabinets High Reliability versions are available (space). Custom design upon request.



DIELECTRIC TRIMMERS:

Ceramic dielectric trimmers allows a lot of combinations (capacitance ranges, voltages, temperature coefficient and also mounting methods). "Thin-Trim®, Ceratrim®, Chip trim®" are widely used for circuit trimming with high stability. Most of them are SMD and are delivered on tape, are RoHS, and can also be provided in non magnetic version.

Air dielectric trimmer capacitors are designed specifically for RF applications with concentric tubular design. They meet MIL-C-14 409 D, and ESA/SCC n°3010, and are RoHS compliant. They are ideal for applications such as mobile radios, aerospace communications, crystal oscillators and filters, radar and numerous other space, military and industrial applications.



Sapphire dielectric trimmers High "0" characteristics, High voltage and various mechanical versions, make ideally suited to power applications in filters and high power amplifiers. They can be also offered in non-magnetic version for medical applications.

FERRITE MATERIALS:

Mostly intended for isolator & circulator widely used in radio-communication systems, Ferrite are offered in disk, triangle or custom-designed dimensions. They

are based on EXXELIA TEMEX formulation, providing low △H propitious to IMD reduction. Their combination with selected dielectric material allows a choice of FDA apparatus, of repute to save space in isolator/circulator.



RESONATORS:

Several dielectric constant ranging www 24 to 78, provide High "Q" factor for applications 1.5 GHz to 100 GHz through materials [E2000 to E7000].

Wide range of applications in DRO's mass production for satellite reception LNB's, radio-communication, Industrial (motion detection sensor), automotive (anticollision radar) etc... Combination of resonators and tuning elements for cavity filters adjustment on request.

Coaxial resonators are generally used in filters, duplexers, CRO's and VCO's applications within a broad range of frequencies: 300 MHz to 6 GHz. They are provided with several dimensions: 2 x 2 to 12 x 12 mm, allowing the best compromise between impedance, "0" factor and resonant frequency.



TANTALUM CAPACITORS

As a result of the manufacturing technology and the constant improvements in tantalum powders, tantalum capacitors offer the highest CV (product capacitance x voltage) per volume combined with very high reliability and durability.

They are particularly used in aircraft and helicopters, radars, missiles, satellites and launchers as well as downhole tools.

EXXELIA TANTALUM develops and manufacture solid capacitors, both $\rm MnO_2$ and Polymer technologies, as well as wet tantalum capacitors.

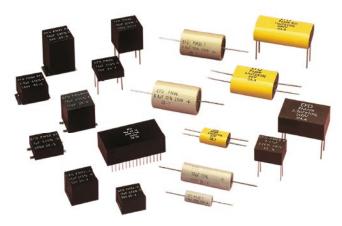
Specific interfaces, package size and characteristics are available upon request.

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		Product range	Detail specification	Capacitance	Voltage	Operating Temperature	Main features
		CT 79 / CT 79 SMD	CECC 30202-005/001/801 ESCC 3003/005	1.7μF ⇒ 1 200μF	6 V ➪ 150 V	−55°C+125°C	High ripple current.
	<u>.e</u>	CT 79E / CT 79E SMD	CECC 30202-005 / 001 / 801 ESCC 3003 / 005	5.6 μF ➡ 2 200 μF	6 V ➪ 150 V	−55°C+125°C	High ripple current. Extended range of CT 79.
	ase - Ax	ST 79 / ST 79 SMD	ESCC 3003 / 006	90μF ⇒ 1800μF	25 V ➪ 125 V	−55°C+125°C	High capacitance.
	alum ca	CLR 79	MIL-PRF-39006/22	1.7μF ⇒ 1 200μF	6 V ⇒ 125V	−55°C+125°C	MIL qualified. Failure rate M.
ទី	led Tant	CLR 81	MIL-PRF-39006/25	6.8μF ⇔ 680μF	25 V ➡ 125V	−55°C+125°C	MIL qualified. Failure rate M.
pacito	IIIy seal	DSCC 93026	DWG N°93026	10μF ⇒ 1 800μF	6 to 125V	−55°C+125°C	DSCC approved.
Wet tantalum capacitors	Hermetically sealed Tantalum case - Axial	CT 79 HT200 - CT 79E HT200 ST 79 HT200	CECC 30202-005/001/801	1.7μF ➡ 2 200μF	6 V ➡ 150 V	−55°C+200°C	High capacitance. High Temperature.
t tanta	H	WT 82	-	33μF ⇒ 82μF	160 V ➡ 170 V	−55°C+70°C	High voltage.
W		WT 83	-	150μF ⇒ 10 000μF	10 V ➪ 125 V	−55°C+125°C	Extended Capacitance - Enhanced performance High reliability design.
	cases	CT 9 - CT 9CR CT 9E - CT 9ECR	CECC 30202-004	3 μF ➡ 2 200 μF	6.3 V ➡ 150 V	−55°C+125°C	Silver case. Glass metal seal. Extended range (CT 9E / 9ECR).
	Silver	CT 4 / CT 4E	CECC 30202-003 (CT4) BS 9073 F008 / F032 (CT 4E)	1.7μF ⇒ 2 200μF	6 V ⇔ 150 V	−55°C+125°C	Silver case. Seal and resin sealing. Extended range (CT 4E).
	Modules	SPE 0844 / SPE 0844S	CECC 30202-009	27μF ⇔ 6 000μF	6 V 🖈 375 V	−55°C+125°C	Paralell / serial assembly of CT79 - CT79E.
	Mod	AP 31 / AP 41 / AS 31	-	27μF ⇒ 40 000μF	10 V ➡ 450 V	-55°C+125°C	Paralell / serial assembly of WT 83.
		CTS 1	CECC 30201-001 / 002 / 801	0.1 μF ⇒ 330 μF	6.3 V ⇒ 125 V	-55°C+125°C	Standard range. General purpose +125°C.
	e - Axia	CTS 13	CECC 30201-005	0.1 μF ⇒ 330 μF	6.3 V ⇔ 63 V	−55°C+85°C	Standard range. General purpose +85°C.
	Hermetially sealed metal case - Axial	CTS 32	CECC 30201-019	1μF ➡ 330μF	6.3 V ⇔ 63 V	-55°C+125°C	Standard range. High surge current. Reverse voltage.
	aled mo	CTS 23	CECC 30201-025	0.1μF ⇒ 1200μF	6.3 V ⇔ 63 V	-55°C+125°C	Extended range. General purpose.
	ially se	CTS 33	CECC 30201-026	0.1 μF ⇒ 1 000 μF	6.3 V ⇔ 63 V	-55°C+125°C	Extended range. Low leakage current.
	Hermet	CTS 21 / CTS 21E	CECC 30201-040	5.6 μF ⇒ 1 000 μF	6.3 V ⇔ 63 V	-55°C+125°C	Low ESR. High ripple current. High surge current. Extended range (CTS 21E).
ors		CTS 20 / CTS 20E *	CECC 30201-022 (CTS 20)	0.22µF ⇒ 560µF	6.3 V ⇔ 63 V	−55°C+125°C	Non-polarized (cathode to cathode coupling of 2 CTS 1 or 23)
tantalum capacitors	ılded dial	CTS 41 / CTS 41 RSE	CECC 30201-037	0.1 μF ⇒ 150 μF	6.3 V ⇒ 50 V	-55°C+125°C	High surge current, Low ESR (CTS 41 RSE).
alum c	Mou Ra	CTS 4	CECC 30201-003	0.1 μF ➪ 150 μF	6.3 V ➪ 50 V	−55°C+85°C	General purpose.
	ount	CTC 3 / CTC 3E	CECC 30801-009 / 801 (CTC 3)	0.1μF ⇒ 680μF	4 V ➡ 50 V	−55°C+125°C	Standard chip size. General purpose. Extended range (CTC 3E).
Solid	face mo	CTC 4	CECC 30801-011	0.1 μF ⇒ 100 μF	6.3 V ⇒ 50 V	−55°C+125°C	Standard chip size. General purpose. High surge current.
	MD sur	CTC 4 RSE	-	4.7μF ⇒ 1 000μF	6.3 V ⇒ 50 V	−55°C+125°C	Low ESR. High ripple current. High surge current.
	ases - S	CTC 21 / CTC 21E	CECC 30801-013 ESCC 3012/002 (CTC 21) 003 (CTC 21E)	5.6μF ⇒ 680μF	6.3 V ➡ 100 V	−55°C+125°C	Low ESR. High ripple current. High surge current. Extended range (CTC 21E).
	Moulded cases - SMD surface mot	SMT 47	-	47μF ⇒ 1 500μF	6.3 V ➪ 63 V	−55°C+125°C	Very high capacitance. High ripple current.
		CTC 42 / CTC 42E	_	12 μF ➡ 1 500 μF	6.3 V 🕏 80 V	–55°C+125°C	Assembly of 2 CTC 21/CTC 21E in parallel.
	d cases D	CTP 21 **	-	22μF ⇒ 560μF	16 V ➡ 100 V	-55°C+105°C	Polymer technology: very high capacitance, very low ESR, high ripple current, high surge current.
	Moulded cases SMD	CTP 42 **	-	47μF ⇒ 1 200μF	16 V ➡ 100 V	−55°C+105°C	Assembly of 2 CTP 21 in parallel.



FILM CAPACITORS



FILM CAPACITORS:

EXXELIA TECHNOLOGIES and EXXELIA DEARBORN manufacture a versatile cast of rugged, metalizedfilm and film foil capacitors. These include film-wrapped, premolded epoxy cased, cast and hermetically sealed metal case capacitors for applications where high-performance, reliability and

Features include AC ratings, high-temperature operation and exceptional stability, low-loss, close tolerances, long-life and high-reliability.

Polyphenylene Sulfide, Polyethylene Naphthalate, FPE, MPF and Teflon.

Configurations include Wrap and Fill, Hermetic Tubular, Axial, Radial, Bath Tub, Lugs, Brackets, Feed Through, Glass Tube, Ceramic Tube, Large Rectangular Cans, Resin Case and Custom.







CP53/54/55

Standard operating ranges are from -55°C to +150°C depending upon dielectric and capacitance values from $0.0001\,\mu\text{F}$ to $2,000\,\mu\text{F}$.

CUSTOM DESIGN CAPACITORS:

EXXELIA offers a wide range of custom design capabilities with respect to Temperature, Capacitance, Frequency and Voltage requirements.

Strong heritage, high reliability and quality of EXXELIA make them perfectly suitable for all challenging environmental conditions and specific interfaces.





	T (℃)	Product range (space grade available in green)
		PM 89-PM 90 (S)-PM 94(S)
Polyester for or S.M.P.S.		PM 96(S) - PM 96 T(S) - MKT(S)
Polye or or S.		PM 948(S) - PM 907(S)
æ		PHM 912
		PM 50 - PM 60
		PM 7 - PM 12 - PM 720 - PM 730
		MPA HT - MRA HT
		BIK-X2/Y - BIK P-X/Y - BIK CR
	ير	205P
_	–55°C +125°C	218P
Polyester	–55°	410P
<u>S</u>		430P
		431P
		442P
		CP53 / 54 / 55
	-65 +125	132P
	-40 +85	409P
		A 64 S4 (T) - A 74 S4 (T) - PMR 4 (T)
		MPA 4 - MKB 4
ffix T)		KCP 4 UA T
P.S. su		KSP 4 UA T
de (P		K1PE T
Sulfi		KM 501-601(T) - KM 50-60(T)
nylene		KM 111 (T)(S)
lyphei		KM 311-21-711-7 (T)
e / Po		KM 78 - 82 - 90 - 97 (T)
bonat		PMR 64 (T) - PMA 64 (T)
Polycarbonate/ Polyphenylene Sulfide (P.P.S. suffix T)		PM 67 (T) - PM 72 (T)
•		KM 94 (S)
		KM 915
		810P
		820P
P.P.S.)		832P
lfide (842P
ne Su		859P
enyle		860P
Polyphenylene Sulfide (P.P.S.)		882P
		PRF-83421/06
		880P
polys- tyrene	_55°C +85°C	PLS 3 - PLS 5 - PLS 7 - PLS 8
High voltage	–55°C +125°C	HT 72 - HT 77
Ŧ Ö	1/4	HT 96 - HT 78(P)(S) - HT 86 (P)(S) - HT 97(P)(S)

Dielectric	Capacitance	Tolerance	Voltage	Qualification	Use
Dielectric	·		_	ESA/ESCC (EPPL, QPL)	030
Metallized	8.2 nF ➡ 150 μF	±5% ⇒ ±20%	50 V ⇒ 630 V	in house (PM 89)	High frequency switch mode power supplies, SMD.
polyester (P.E.T.)	33 nF ⇔ 100 μF	±5%	25 V ⇔ 630 V	Acc. ESA	defense aeronautic
	22 nF 🕏 180 μF	±10 % ±20 %	63 V ➡ 1250 V	ESA / ESCC	• space
Metallized plastic film	1.8 μF ➡ 68 μF	±10 % ±20 %	250 V ➡ 1000 V	in house	
	1 nF 🕏 22μF	±5 % ⇒ ±20 %	40 V ➡ 630 V	CECC / IEC	
Metallized polyester	82 pF ⇒ 10 μF	±5 % ⇒ ±20 %	63 V ⇒ 630 V	CECC / IEC	Standard applications.
	1 nF ➡ 4.7 μF	±5% ⇒ ±20%	1000 V ⇒ 15000 V	in house	11
Metallized polyester Metallized polypropylene	1 nF ➡ 6.8μF	±5% ⇒ ±20%	400 V _{DC} - 250 V _{AC}	in house	
	1 nF 🖈 0.5 μF	±20% ⇒ ±10%	2 000 ➡ 10 000 V		High Voltage
	1 nF 🖈 12.0μF	±20% ⇒ ±5%	100 ➡ 400 V	MIL QPL	
	1 nF 🕏 5.0μF	+20% −10% 🕏 ±10%	50 ⇔ 600 V		
	1 nF 🖈 10.0 μF	±20% ⇒ ±5%	63 ⇒ 16 000 V		High Voltage
Polyester (P.E.T.)	10 nF 🖈 15.0 μF	±20% ⇒ ±5%	63 ⇔ 630 V		
	10 nF 🕏 10.0 μF	±20% ⇒ ±5%	63 ⇔ 400 V		AC / DC Current
	50 nF 🖈 10.0 μF	+20 −10% ⇒ ±10%	100 ➡ 1 000 V		
	1 nF 🖈 1.0 μF	+20% −10% ⇒ ±10%	100 ➡ 1 000 V	MIL QPL	
	0.10µF ➡ 0.5µF	+20% −10% ⇒ ±10%	50 ➡ 1 000 V		EMI Suppression
Metall. polycarbo. / P.P.S.	1 nF ➪ 33 μF	±1 % ⇒ ±20 %	40 V ➡ 630 V	NF F 62 102	
Metallized polyester	1 nF ➡ 22 μF	±5% ⇒ ±20%	40 V ➡ 630 V	NF F 62 102	
Film-foil / P.P.S.	7.5 nF ➡ 77.7 nF	±2 % ±5 %	630 V ⇒ 1000 V	Acc. NF F 62 102	Safety capacitors for signalling and others railways applications.
Film-foil / P.P.S.	10 nF ➡ 0.2 μF	±1% ⇒ ±20%	400 V ➡ 1500 V	Acc. NF F 62 102	and others raintage approaches.
Metallized P.P.S.	10 nF 🕏 3.3 μF	±1%	400 V ➡ 630 V	NF F 62 102	
	1 nF ➡ 22μF	±1% ⇒ ±20%	40 V ➡ 630 V	CECC	
	1 nF 🖈 10 μF	±1% ⇔ ±20%	40 V ➡ 400 V	ESA (EPPL) / CECC	
Metallized	1 nF ➡ 22 μF	±1% ⇒ ±20%	40 V ➡ 630 V	CECC	Precision capacitors (Capacitance stability, low tolerance)
polycarbonate / P.P.S.	1 nF 🖈 10 μF	±1% ⇔ ±20%	40 V ⇔ 208 V	in house	Measurement, control electronics.
	470 pF ➡ 22 μF	±1% ⇒ ±20%	40 V ➡ 630 V	in house	AC filtering (400 Hz and others).
	1 nF ➡ 15 μF	±1%	40 V ➡ 208 V	in house	
	1 nF ➡ 1.2μF	±1% ⇒ ±20%	40 V ➡ 100 V	ESA/ESCC (EPPL)	High stability, SMD.
Metallized P.P.S.	1.5 nF ➡ 2.7 μF	±5% ⇒ ±20%	250 V _{DC} ⇔ 630 V _{DC} 150 V _{AC} ⇔ 400 V _{AC}		AC Filtering
	1 nF ➡ 1.0 μF	±20% ⇒ ±5%	50 ➡ 400 V		
	10 nF 🖈 15.0 μF	±10% ⇒ ±1%	50 ⇒ 400 V	MIL QPL	
	1 nF ➡ 10.0 μF	±10% ⇒ ±2%	63 ⇒ 400 V		
	10 nF ➡ 15.0 μF	±10% ⇒ ±2%	50 ⇔ 200 V		
Polyphenylene Sulfide (P.P.S.)	10 nF ⇒ 10.0 μF	±20% ⇒ ±5%	80 ⇒ 440 V _{RMS}	MIL QPL	Precision capacitors Low TCC
	10 nF 🖈 10.0 μF	±20% ⇒ ±5%	126 ⇔ 250 V _{RMS}	MIL QPL	
	1 nF – 0.22 μF	±10% ⇒ ±2%	200 V		
	1 nF ➡ 22 µF	±10% ⇒ ±0.25%	30 ⇒ 400 V	MIL QPL	
	4.7 nF ⇒ 10.0 μF	±10% ⇒ ±2%	50 ⇒ 400 V		
Polystyrene + foil	10 pF ➡ 1 μF	±1% ⇒ ±5%	63 V ⇒ 500 V	CCTU/CECC	Filtering, frequency tuning.
39	•				
Composite resin impregnated	100 pF ➡ 4.7 μF	±5%	630 V ⇒ 25 000 V	in house	High voltage filtering. • defense

FILM CAPACITORS

EXXELIA TECHNOLOGIES and **EXXELIA** DEARBORN film capacitors have exceptional stability, low-loss, long life, and high reliability. They are exceptional for pulse/storage, DC link, energy discharge, and custom applications.

MICA CAPACITORS:

Capacitors with mica dielectric are noted for their excellent characteristics such as: temperature performance, low loss at all frequencies, high dielectric strength and stability over time.

They are particularly recommended for use in filtering circuits, delay line circuits, oscillators, pulse circuits, H.F. generators, emission lines, D.C. blocking circuits, coupling, measurement etc.



	T° (℃)	Product range (space grade available in green)	Dielectric	Capacitance	Tolerances	Voltage range	Qualification	Use
ā	.c	PP 04 - PP 05	Metallized polypropylene	330 pF ➡ 6.8 µF	±5% ±10%	250 V ⇒ 2 500 V	in house	High current pulses, protection circuit high frequencies
Metallized polypropylene	(+105	PP 3 A - PP 3 M PR 3 A - PR 3 M	Metallized polypropylene+foil	680 pF ⇒ 1μF	±5% ⇒ ±20%	630 V ⇒ 3 500 V	in house	AC and pulse current
lypro	J.88+	PM 98 - PM 980 - PM 981	Metallized plastic film	25μF ➡ 1 600μF	\pm 10 % \pm 20 %	300 V ⇒ 1 200 V	in house	Filtering, energy storage, flash
ed pc	40°C -	PP 78 A - PP 78 R - PP 78 S	Metallized polypropylene	1 nF 🖈 10.2 μF	±1% ⇒ ±20%	160 V ⇒ 630 V	UTEC/NFC	AC/DC current, standard applications
etalliz	-55) –	PPS 13 - PPS 16 A - PPS 16 R PP 318 - PP 418	Polypropylene + foil	100 pF ➡ 603 nF	±1% ⇒ ±20%	63 V ➡ 1000 V	in house	AC/DC and pulse current
ž		RA PS	Metallized polypropylene+foil	100 pF ⇒ 22 μF	±1% ⇒ ±20%	630 V ⇒ 2 000 V	in house	AC and pulse current
	+40°C	682P		5.0μF ⇒ 100μF	+20% -10%, ±10%	800 ➡ 1 200 V		Energy storage
	7+0	684P		5.0µF ⇒ 175µF	$+20\% -10\%$, $\pm 10\%$	400 ➡ 1 000 V		
	-55 +70	730G		0.01µF ⇒ 2.5µF	±20% ⇒ ±5%	850 ⇔ 3 000 V		AC / & Snubber
	-55 +85	781P		18.0µF 🕏 400.0µF	±20% ⇒ ±10%	600 ➡ 1 800 V		
(P.P)		700P		0.01µF ⇒ 1.0µF	±20% ⇒ ±5%	200 ⇒ 800 V		
Polypropylene (P.P)		709G	Polypropylene	1 nF 🖈 4.7 μF	±20% ⇒ ±5%	160 ➡ 2 000 V		AC / DC & Pulse current
propy		710P	(P.P)	1 nF 🖈 1.0 μF	±20% ⇒ ±5%	200 ⇒ 800 V	MIL QPL	
Poly	+105°(730P/731P		22 nF 🖈 10.0 μF	±20% ⇒ ±5%	160 ⇒ 630 V		AC / DC & Pulse current
	-55°C	734G		0.47µF ⇒ 10.0µF	±20% ⇒ ±5%	400 ➡ 600 V		Low inductance
		735P		1.0µF 🕏 30.0µF	±20% ⇒ ±5%	100 ⇒ 400 V	MIL QPL	SMPS
		744G		0.47µF ⇒ 3.5µF	±20% ⇒ ±5%	600 V		
		752P		0.10µF ⇒ 2.5µF	±20% ⇒ ±5%	800 ⇔ 3 000 V		IGBT Snubber
	ں	118P		1 nF 🕏 12.0 μF	$\pm 20\%$ to $\pm 5\%$	200 ⇒ 1 000 V	MIL QPL	Bypass, coupling
	+125°	103P		1 nF 🖈 1.0 μF	$\pm20\%$ to $\pm10\%$	200 ⇒ 600 V	MIL QPL	RFI
_	- 55°C +	911P		0.10μF ⇒ 2.7μF	10%	400 V		
Paper / Foil		CL53/54/55	Paper / Foil	0.05μF ⇒ 10μF	$+20\% -10\%. \pm 10\%$	100 ⇒ 1 000 V	MIL QPL	Bypass, coupling, filtering High temperature +200°C
Papeı	2°C	131P	r apor / r on	1 nF 🖈 1.0 μF	$\pm 20\%$ to $\pm 5\%$	200 ⇒ 1 000 V	MIL QPL	
	-6 +12	CQ72		0.10µF ⇒ 15.0µF	±20% ⇒ ±10%	400 ➡ 12 500 V	MIL QPL	High Voltage
	.40°C	282P		10.0μF ⇒ 200μF	$+20\% -10\%. \pm 10\%$	2 000 ⇒ 4 000 V		Energy storage
	0	681P		5.0μF ⇒ 100μF	+20% -10%. ±10%	1 000 🖈 2 500 V		Energy storage
"	100]	PPA - PPA FR - PPA M		1.5 μF ⇒ 260 μF	±5% ⇒ ±20%	260 V _{AC} ⇒ 900 V _{AC}	in house	Motor run, fluorescence, compensation
ronics	+) ລູເ	PP 44 R/A - PP 411 PP 44 RS - 44 A2	Metallized polypropylene	0.1 μF ⇒ 400 μF	±5% ⇒ ±20%	300 V ⇔ 2400 V	in house	IGBT capacitors, protection / turn off thyristors GTO, medium frequency
elect	ູດ +85	PP 88 - IGB 99		47 nF ⇔ 7.5 μF	±5% ⇒ ±20%	800 V ➡ 4000 V 1.5kV _{GTO} ➡ 5.6kV _{GTO}	in house	tuning
Power electronics) –40	PLP PAM	Impregnated P.P +paper	22 nF 🖈 300 μF	±5% ⇒ ±20%	160 V ⇒ 10000 V	in house	Commutation, rapid discharges, energy storage, filtering, protection
	[-22]	BI 73 A - BI 73 R R 73 A - R 73 R	Bi-film Polyester + foil	1 nF 🖈 2.2 μF	±5% ⇒ ±20%	1000V _{DC} ⇒ 2200 V _{DC} Ucrete ⇒ 5000 V	in house	Filtering, protection
	+125°C	CA 1 - CA 2 CA 17 to CA 19		4.7 pF 🖈 100 nF	$\pm 0.5 \mathrm{pF}$ or $\pm 1 \% \Rightarrow \pm 10 \%$	500 V ⇔ 5000 V		Filtering circuits, delay line circuits, oscillators, pulse circuits,
Mica	ن	CA 15 - 20 - 30 - 40 CA 152 to 158	Silvered mica	4.7 pF ⇒ 15 nF	±1pF or ±1 % ⇒ ±10%	63 V ⇒ 500 V	CECC Acc. MIL C 5	H.F. generators, emmission lines, D.C. blocking circuits, coupling,
	-52°	CM 04 to CM12 CMR 03 to CMR 07		1 pF 🖈 91 nF	$\pm 0.5 \text{pF}$ or $\pm 1 \% \Rightarrow \pm 5 \%$	50 V ⇔ 500 V		measurement



ELECTROLYTIC ALUMINUM CAPACITORS

Electrolytic aluminum capacitors delivers the highest capacitance levels (up to 2.2 Farad) compared to all capacitor families. They are particularly suitable for D.C voltage applications in energy storage (lighting flash-lamps, welding machines, radiology, radars) and time delay devices.

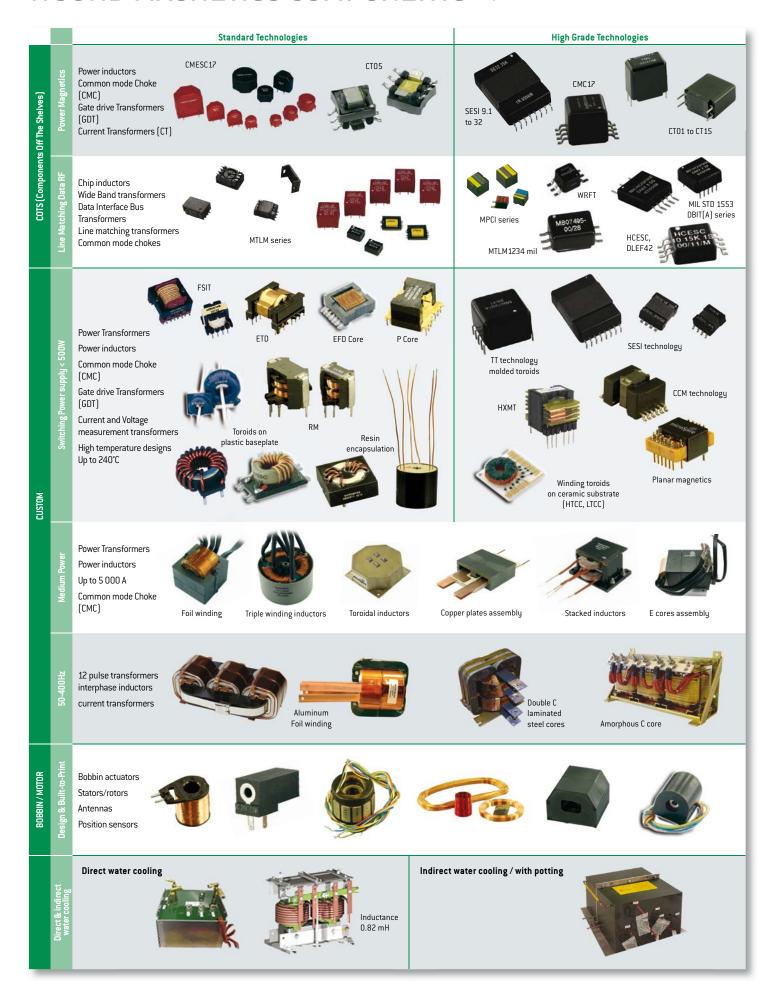
EXXELIA SIC SAFCO product portfolio includes many capacitor styles: screw terminals, radial leaded, snap in and axial. The company also manufactures its own electrolytes enabling to achieve the longest lifetime in the market and to develop high-end solutions dedicated to medical, weapons and aircraft applications.



	(℃)	Product range	Sizes 0 x h (mm)	Capacitance	Voltage	Main characteristics
	-55 +125	FELSIC 125FRS	36x52 to 90x145	220 to 150 000 μF	16 to 350 V	Low ESR, +125°C
		FELSIC 105TFRS	36x47 to 77x144	470 to 68 000 µF	10 to 100 V	Very low ESR
	١+105°	FELSIC HV	51x81 to 90x200	1 000 to 47 000 μF	160 to 450 V	Extreme Long life, High ripple
nals	–55°C to +105°C	FELSIC 105	36x52 to 90x200	100 to 470 000 μF	16 to 450 V	Extreme Long life
Screw terminals		FELSIC 105 LP	90x67	1 500 to 220 000μF	10 to 450 V	105 with Low Profile can
Scre		FELSIC CAPAX	36x44 to 90x200	100 μF to 2.2 F	10 to 500 V	High energy density
	55°C to +85°C	FELSIC 85	36x52 to 90x200	68 to 680 000 µF	10 to 630 V	Standard 85°C
	–55°C t	FELSIC 85M	36x52 to 90x200	68 to 680 000 µF	10 to 630 V	Standard 85°C \pm 20% tolerance
		FELSIC 039- FELSIC 037	36x47 to 77x144	100 to 150 000 μF	10 to 400 V	Standard CO39 type (railway maintenance standard)
e e	-55°C to 145°C	ALSIC 145 20g	18x20 to 22.5x25	470 to 2 200 μF	10 to 115 V	High temp. range, Long life, withstand 20g vibrations
Radial leaded type		CUBISIC	35x35x16. 35x50x16	100 to 33 000 μF	10 to 450 V	Non cylindrical case, Withstand 20g vibrations, High energy density
adial lea	-55°C to +105°C	CUBISIC LP	45x35x12 to 45x75x12	220 to 68 000 μF	10 to 400 V	Non cylindrical case, Withstand 20g vibrations, High energy density
<u>~~</u>	-55°	ALSIC 20g	18x20 to 35.5x25	33 to 80 000 μF	10 to 500 V	Withstand 20g vibrations
	-55	Snapsic 125	22x25 to 35x50	470 to 47 000 μF	16 to 100 V	High temperature range, Long Life
		Snapsic HV	22x25 to 35x50	47 to 2 200 μF	160 to 500 V	Long Life, High ripple current
	55°C to 105°C	Snapsic 105	22x25 to 35x50	22 to 68 000 µF	16 to 500 V	Standard 105°C type
Snap in type		Snapsic 105 4P	35x50 to 45x75	330 to 150 000 μF	16 to 550 V	Standard 105°C type with 4Pins
Snapi		Snapsic 105 LP	45x21 to 45x40	150 to 68 000 µF	16 to 500 V	Low Profile 105°C with 4 Pins
	2 پر	Snapsic Capax	22x25 to 35x50	33 to 47 000 μF	25 to 500 V	High energy density
	55°C to 85°C	Snapsic	22x25 to 35x50	22 to 47 000 μF	16 to 500 V	Standard 85°C type
		Snapsic 4P	35x50 to 45x100	330 to 150 000 μF	16 to 500 V	Standard 85°C type with 4 Pins
	–55°C to +150°C	Prorelsic 145	14x30 to 25x75	6.8 to 10 000 μF	16 to 450 V	High temperature Long life
ø	-55 +15	Vacsic 150	14x30 to 16x30	6.8 to 3 300 µF	16 to 450 V	High temperature Long life, Withstand 45g vibrations
Axial type	-55 +125	Prorelsic 125	12x25 to 25x75	1 to 15 000 μF	10 to 350 V	125°C Long life
4	+105°C	Sical /Sical CO42	6.5x19 to 25x75	6.8 to 47 000 μF	10 to 630 V	Standard 105°C type
	-55 to +105°	Vacsic 105	12x25 to 16x30	15 to 4 700 μF	10 to 450 V	Standard 105°C type; Withstand 45g vibrations.



WOUND MAGNETICS COMPONENTS



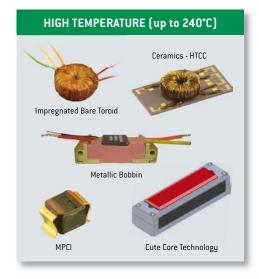


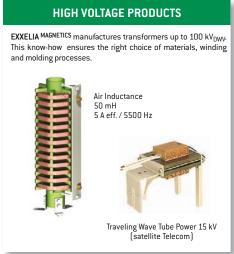
EXXELIA MAGNETICS, EXXELIA RAFTABTRONICS and EXXELIA DEYOUNG specialize in the design, manufacture and sale of magnetic components, including wound magnetics, inductors, transformers, motors, sensors and actuators for high performance applications.

Our technology offer includes standard linear and toroidal technologies, as well as Chameleon Concept Magnetics technology (CCM), Toroidal Transfer

Molded Technology (TT), SESI planar/low profile technology, and Aluminum Foil Winding technology (AFW) all optimized to meet the most demanding applications.

EXXELIA offers a complete range of products, providing solutions for highly demanding requirements such as High Voltage, High Temperature, and Power Levels up to 300 kVA.

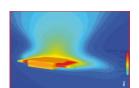


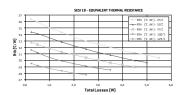


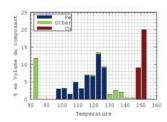


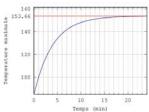
THERMAL MANAGEMENT

EXXELIA invests in R&D and makes extensive studies on the thermal management of magnetics, including loss calculations, design rules, thermal resistance and thermal modeling. We have available, a complete database of thermal resistances for all standard magnetics packages and have developed specific software for designing optimized compact components.









CATALOG PRODUCTS

	Series	Current	Inductance	Temperature Range	Frequency	Notes
ь	MPCI 10000, 12000, 20000	15 mA 🖈 1 000 mA	0.010 µН ➪ 1 000 µН	-55°C ⇔ +125°C	7.9 MHz ➡ 500 MHz	QPL, Space Qualified
Chip	MPCI H01	100 mA 🖈 1 500 mA	0.38μH ⇒ 100μH	-55°C ➪ +125°C		QPL, Space Qualified
-	MPCI 233 H01	100 mA 🖈 1 500 mA	0.38µН ➪ 100µН	up to +175°C		High Temperature
C.Mode Choke	CMC 15, CMC 18, CMC 22	0.55 A ⇒ 14.3 A	60µН ➪ 4 900µН	–55°C 🖈 +125°C		QPL, Space Qualified
프린	CMC 14, CMC 17	1.1 A ➡ 11.7 A	140µH ➡ 69 200µH	-55°C ➪ +125°C		
5	SESI 9.1	0.045 A ⇒ 6 A	1μH ➪ 6 800μH	–55°C 🖈 +125°C	max 1 MHz	QPL, Space Qualified
nductor	SESI 14, 15	0.28 A ➡ 14 A	1.5µH ⇒ 2 290µH	-55°C ➪ +125°C	max 1 MHz	QPL, Space Qualified
=	SESI 18, 22, 32	0.8 A ⇒ 24 A	4.9μH ⇒ 4 709μH	-55°C ➪ +125°C	max 1 MHz	QPL, Space Qualified
	Series	ET	Turn Ratio	Temperature Range	Frequency (duty cycle 50%)	Notes
cate drive transfo.	GTD 15	60/80 Vµs	1:1.52/1:1:1	–55°C 🖈 +125°C	up to 500 kHz	Aeronautic, Space
tran	GTD 91	50/135 Vµs	1:1/1:1:1	-55°C ⇔ +125°C	up to 500 kHz	Aeronautic, Space
	Series	Current	Turn Ratio	Temperature Range	Frequency (Triangle Waveform)	Notes
Current transfo.	CT 15	17 A pk max.	1:50/1:200	-55°C ➪ +125°C	6 kHz ➡ 100 kHz	Aeronautic, Space
tran tra	CT 91	10 A pk max.	1:50/1:200	-55°C ➪ +125°C	6 kHz ➪ 500 kHz	Aeronautic, Space
	DBIT / SBIT	MIL-STD-1553 Data	Bus Transformer	–55°C 🖈 +125°C	75 kHz ⇔ 1 MHz	Aerospace, ESA / EPPL



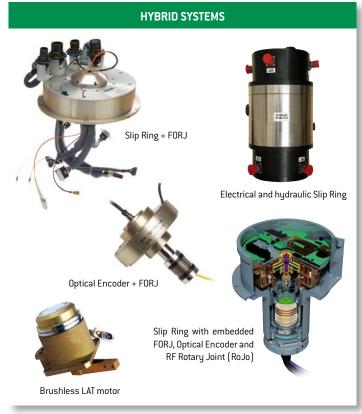
POSITION SENSORS & SLIP RINGS

EXXELIA TECHNOLOGIES designs and manufactures contact and contactless Position Sensors, Slip Rings and Hybrid Systems.









PRECISION MECHANICS

EXXELIA's Precision Mechanics division specialises in machining complex parts, from prototypes to medium series. Our best-in-class palletized-5-axis turning and milling equipment enable us to work with all types of material including titanium, inconel, 35NCD4 etc...

Assembly, high precision manual deburring and hydraulic tests can be carried out in our workshop





EMI-RFI FILTERS



EXXELIA TECHNOLOGIES designs and manufactures EMI-RFI filters in different low pass configurations $[C, L, Pi, T, 2 \times Pi, 2 \times L \text{ and } 2 \times T]$ intended to protect electronic equipment from interferences.

Capacitors are a key components in a filter and thanks to its expertise in the field, EXXELIA TECHNOLOGIES is able to manufacture high-end solutions combining performance and reliability.

С	L	Pi	Т
• = •	· ~~~	· = ~~~~	o/mmm- <u>=</u> /mmm-o
<u></u>	<u> </u>		<u></u>
20 dB / decade	40 dB / decade	60 dB / decade	60 dB / decade
20 db / decade	40 db / decade	ou db / decade	60 dB / decade

	T°	Model	Current	Voltage	Performance	Qualification	Use
EMI-RFI Filters	-55°C +125°C (up to 175°C)	Feedthrough 0 3 - 0 4 - 0 6 - 0 10 (mm)	Up to 15 A	Up to $500\mathrm{V}_\mathrm{DC}$ and $115\mathrm{V}_\mathrm{AC}400\mathrm{Hz}$	Up to 80dB from 10 kHz to 10 GHz	Qual. ESA, Air, Compliant MIL 461, DO 160	Space, Aeronautic, Defense, Industry.
		Feedthrough 0 17 (mm)	Up to 30 A	Up to 3 000 V_{DC} and 200 V_{AC} 400 Hz	Up to 80dB from 10 kHz to 10 GHz	Air qualified, Compliant MIL 461, D0160	Aeronautic, Defense, Industry.
		Multi ways Filters	Up to 15 A	Up to 500 V_{DC} and 115 V_{AC} 400 Hz	Up to 80dB from 10 kHz to 10 GHz	in house	Aeronautic, Defense, Industry.
		Surface mount FCMS - CFCMS	10 A (20 A for HI version)	Up to 500 V_{DC} and 115 V_{AC} 400 Hz	Up to 70 dB from 10 kHz to 10 GHz	ESA EPPL	Space, Aeronautic, Defense, Industry.
		SPF	0.1 A ➡ 500 A	25 V ➡ 3 000 V eff.	1 kHz ➡ 10 GHz	in house	Custom design

ENERGY FILTERS

Following 50 years heritage in Defense market, EXXELIA TECHNOLOGIES offers highly performant, robust and reliable solutions to protect from different EMC phenomenon all kind of signal such as:

- Power supply,
- Control lines,
- Data communication...





	T°	Model	Current	Voltage	Performance	Use
	J. 58+ J. 52-	Feedthrough Tube filters	Up to 500 A	Up to 1 000 $\rm V_{DC}$ and 400 $\rm V_{AC}$	Up to 100 dB Up to 18 GHz	Single lines power supply.
Filters		Power cabinets	Up to 2 500 A	Up to 440 V _{AC} (50-800Hz)	Up to 100 dB from 10 kHz to 18 GHz	Three or single phase power supply for TEMPEST and HEMP
EMCF		Data communication	Up to 1A	-	Up to 100 dB Up to 18 GHz	Up to 100MHz bandwidth data signal for TEMPEST and HEMP
		Custom filters	Additional protection for energy and signal filtering.			

COMPONENTS & SUB-ASSEMBLIES MANUFACTURING



With two production units, separated by less than 10 km and located both in Casablanca (Morocco), **EXXELIA MAROC** offers to its customers a subcontracting capability on its two main competences fields with high technology processes as: wire bonding, vacuum metallization, RF test equipments, reliability test equipment.

Complex electronic modules or components assembly:

- RF diodes packaging,
- RF circulators assembly,
- quartz hybrid oscillators assembly,
- high frequency filters assembly,
- opto electronic components,
- antennas, sensor.

Built-to-print for overmoulding, wiring and harnessing, rotors, stators, actuators.

EXXELIA VIETNAM is locate in Ho Chi Minh City and dedicated to Medium to High volume markets requesting traceability for processes and raw materials.





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